# Update on the Frequency Noise Budgeting and Controls

**Daniel Sigg** 

LIGO Hanford Observatory

Commissioning Meeting July 12, 2019

1

G1901316-v1

- □ Frequency noise coupling to DARM tends to be non-negligible for f>~1kHz
- Frequency noise coupling to DARM flattens out due to higher order mode couplings at >100Hz, measured 1-2 x 10<sup>-15</sup> m/Hz (also ~flat in W/rad)
- Frequency noise coupling depends on differential heating Can only get worse the higher the power



Power spectrum



G1901316-v1

Avg=30/Bin=23L

T0=08/07/2019 17:25:44



## Available Options for VCOs (SAW)

- Advanced LIGO VCO: 79.4±1.2MHz
  1.05±0.14 GHz VCO (MCF91119-10) divide by 128 & mix with 71 MHz OCXO
- Initial LIGO VCO: 80±5 MHz
  800±50 MHz VCO (CRO750SA) divide by 10
- Best available SAW VCO: 79.6±1.2MHz 1.595±0.025GHz VCO (DCRO159161-12) divided by 20
   80 MHz VCO wideband (e.g., DCMO514-5)



## Are we gain limited at high frequencies?

- □ Hierarchical approach: PSL ~ 500kHz BW, IMC ~100kHz BW
- □ No reference cavity: IMC ~500kHz BW, current TTFSS
- Serial approach: PSL ~500kH BW, IMC ~500kHz BW Requires IMC TTFSS and separate EOM

Conclusion: Serial approach & increasing modulation index will help >1kHz and allow for increased VCO noise



### Interferometer Projection (assuming ideal IMC sensing noise)

- □ Hierarchical approach: PSL ~ 500kHz BW, IMC ~100kHz BW, REFL ~15kHz BW
- □ No reference cavity: IMC ~500kHz BW, current TTFSS, REFL ~15kHz BW
- Serial approach: PSL ~500kH BW, IMC ~500kHz BW, REFL ~15kHz BW Requires IMC TTFSS and separate EOM

Below a 3-5 kHz: REFL sensing noise dominates



### Interferometer Projection (Comparing IMC sensing noise)

- □ Hierarchical approach: PSL ~ 500kHz BW, IMC ~100kHz BW, REFL ~15kHz BW
- □ No reference cavity: IMC ~500kHz BW, current TTFSS, REFL ~15kHz BW
- Serial approach: PSL ~500kH BW, IMC ~500kHz BW, REFL ~15kHz BW Requires IMC TTFSS and separate EOM

Above 3-5kHz: Better IMC sensing noise is required to take advantage of any REFL improvement



# REFL Sensing (LHO)

### □ REFL shot is high (estimate 10x over ideal): carrier dominated

	Input		AS (contrast?)		POP	REFL		Expect
Carrier	97.6%	37W	19.4%	=25mW	98.4%	82.5%	8.5mW	
9.1 MHz	0.9%	0.33W	6.3%	8mW	1.3%	3.9%	0.4mW	~4mW
45.5 MHz	1.5%	0.56W	74.3%	96mW	0.3%	13.6%	1.4mW	

Total AS port power is 240-270mW; numbers need to be multiplied by 2 to account for OMC.

REFL split ratio 1.25%, unlocked ~400mW.

40-50% of 45.5MHz sideband power is not accounted for.

70-80% of 9.1MHz sideband power is not accounted for: Loss where/why? Recommendation:

- Investigate the 9.1MHz vanishing act
- > Check carrier mode matching and high order mode content in reflection
- > Maybe consider new RM with better optimized coating
- > Increase REFL power (maybe limited by RF signals due to sideband imbalance)

## **Possible Actions**

- □ Unknown prospects to reduce the frequency noise coupling
  - > Higher power and improved squeezing will make frequency noise coupling more significant

#### □ Investigate 9MHz sideband mystery

- > Is the poor sideband power related to optical distortions by the ITMs which produce HOMs?
- > Does this correlate with the high frequency noise coupling?

#### □ Increase power in REFL

- ➢ We are using 2 PDs at LHO already
- > Power is only 5mW/PD at 37W input, but RF signals tend to be large
- □ Reduce carrier in reflection by adjusting RM reflectivity
  - ➢ Is the REFL power dominated by carrier TEM00?
- □ New VCO: Propose to try 1.6GHz device
  - ➢ What's the excess noise seen by IMC-F above 3kHz?
- □ IMC sensing noise reduction (higher modulation index)
  - Dedicated EOM for IMC or dedicated electrode on existing EOM?
  - > TTFSS for IMC (better performance by keeping reference cavity)
  - > Neither will help <3kHz unless we also improve the REFL sensing noise